Alteration details - 2005-06 drilling					
BHID	**FROM**	**TO**	**ALT INTENSITY**	**ALTEXT**	**ALTMIN**
MCD020	0	13	4	P	CyLiHe
MCD020	13	30	3	L	SeSi, Cy
MCD020	30	32.9	4	L	SeSi,Cy
MCD020	32.9	37.3	4	P	SiSe
MCD020	37.3	45.4	4	P	SiSe
MCD020	46.7	47.5	4	P	SiSe
MCD020	48.8	49.9	3	P	SiSe
MCD020	49.9	58.8	3	P	SiSe
MCD020	58.8	77.8	3	F,M	Se,SiSe
MCD020	77.8	80.9	3	P	SeSi
MCD020	80.9	86.5	3	P	Se
MCD020	86.5	89.4	3	P	Se
MCD020	89.4	100.6	3	F,M	Se,SiSe
MCD021	0	3.15	4	P	SiSeLi
MCD021	3.15	6.6	4	P	SiSeBa
MCD021	6.6	13.7	4	P	SiSe
MCD021	13.7	16.8	4	F,M	SiSe,SiSePy(Ba)
MCD021	16.8	22.45	5	F,M	SiSe,Ba
MCD021	22.45	38.2	4	F,M	SiSe, SiSe(Ba)
MCD021	38.2	39.6	4	F,M	SiSe,Ba
MCD021	39.6	58.4	4	F,M	SiSe, SiSe(Ba)
MCD021	58.4	67.9	4	F,M	SiSe,SiSePyBa
MCD021	67.9	89.4	4	P	SiSe
MCD021	89.4	96.6	4	P	SeSi
MCD021	96.6	98.6	3	L	Cy
MCD021	98.6	104.9	4	P	SeSi
MCD021	104.9	106.45	4	P	Se
MCD021	106.45	119	4	P	Se(SeSi)
MCD021	119	120.2	4	P	SiSe
MCD022	0	8.6	2	P	SeSi
MCD022	8.6	12.2	3	F,M	SeSi,SiSePy
MCD022	12.2	23.1	3	P	SeSi
MCD022	23.1	25.95	3	F,M	SeSi,SiSePy
MCD022	25.95	47.9	2	P	SeSi
MCD022	47.9	57.2	3	P	SeSi
MCD022	57.2	64.15	4	P	Se(Si)
MCD022	64.15	71.4	4	L	Se
MCD022	71.4	82.9	3	P	SiSe
MCD022	82.9	83.9	4	F,M	SeSi,Si
MCD022	83.9	84.7	4	P	Si
MCD022	84.7	87.7	4	L	Si
MCD022	87.7	89.45	4	P	Si
MCD022	89.45	93.7	4	P	Si
MCD022	93.7	97.65	4	P	SiSe
MCD022	97.65	120.2	3	F,M	Se,SiSe
MCD023	1.7	4	4	P	Cy
MCD023	4	11.9	4	P	CyLi
MCD023	11.9	14	3	P	CyCl
MCD023	14	19.2	4	P	CyLi
MCD023	19.2	21	4	P	CyLiSe
MCD023	21	28.9	3	P	CyLi
MCD023	28.9	31.2	3	P	Se(Li)
MCD023	31.2	38.8	3	P	Se(Si)
MCD023	38.8	63.7	3	P	SiSe
MCD023	63.7	88.6	3	P	SeSi
MCD023	88.6	100.7	3	P	SiSe
MCD024	0	13.2	4	P	CyLi
MCD024	13.2	18.5	3	P	CyLi(Cl)
MCD024	18.5	29.4	2	P	CyLiCl
MCD024	29.4	30.9	2	P	Cl
MCD024	30.9	42	2	F,M	SeHe,SeSi

MCD024	42	45	2	P	SeHeCl
MCD024	45	60.05	3	P	SiSe(Cl)
MCD024	60.6	61.4	3	F,M	SiSe,Cl
MCD024	61.4	68.3	2	P	SiSe
MCD024	68.3	73.7	3	P	Se(Si)
MCD024	73.7	77.1	3	F,M	SiSe,Cl
MCD024	77.1	94.9	3	P	SeSi
MCD024	94.9	99.7	3	P	SiSe
MCD024	99.7	100.2	3	P	SeSi
MCD025	0	6.4	5	P	LiCy
MCD025	6.4	7.1	1	L,F,M	ClLi
MCD025	7.1	16.4	3	P/L	LiCy, Cl, Li
MCD025	16.4	18.5	3	L/P	ClCy
MCD025	18.5	37.2	4	P,M	ClSeCy, SiClSe
MCD025	37.2	53.8	4	P	SeSi
MCD025	53.8	65	4	P	SiSe, SiSeCl
MCD025	65	97.8	4	P	SiSeCl
MCD025	97.8	126.5	4	P	SiSe
MCD025	126.5	128.1	5	P	SiClSe
MCD025	128.1	134.8	4	p	SiSe
MCD026	0	23.5	5	P	LiHtCy/SiSe
MCD026	23.5	34.8	5	P	SiSeCl(Py)
MCD026	34.8	37	4	P	SiSe
MCD026	37	39.3	4	P	SiSeCl
MCD026	39.3	40	5	P	CySe
MCD026	40	42.7	4	P	SiClSe
MCD026	42.7	51.5	5	P	SiClSe(Ba)
MCD026	51.5	55	5	P	SiCl(Py)Se
MCD026	55	78.9	5	P	SiCl(Py,Ba)Se
MCD026	78.9	82.5	5	P	SeCl(Py,Ba)Si
MCD026	82.5	95.5	5	P	ClSiSe(Py,Ba)
MCD026	95.5	98.3	5	P	ClSe(Py)Si
MCD026	98.3	119.8	5	P	ClSe(Py)Si(Ba)
MCD027	0	15.1	4	P	SiSe,LiCy
MCD027	15.1	28.25	5	P	SiSeClBaFu
MCD027	28.25	34.9	5	P/Vn	Ba,SiCl
MCD027	34.9	52.5	4	P	SiClSeBa
MCD027	52.5	67.3	5	P	SiSeCl
MCD027	67.3	85.1	5	F	SiSe
MCD027	85.1	91	5	P/F	ClSe
MCD027	91	95	5	P/L	SiSe
MCD027	95	106.6	5	P	SiSe
MCD028	0	1.4	5	P	SiSePy
MCD028	1.4	24.1	4	P	SiSeClPy
MCD028	24.1	41.6	4	P	SiSeClPyFu
MCD028	41.6	48	4	P	SiSeClPy
MCD028	48	70	4	P	SiSePyClFu
MCD028	70	91.8	4	P	SiSeClPyFu(Ba)
MCD028	91.8	92.1	5	P	SiPy(Ba)
MCD028	92.1	95.1	4	P	SiSePyFu
MCD028	95.1	119.5	5	P	SiSePyCl(BaGaSp)
MCD028	119.5	150	5	P	SiClSePyCy(BaGaSp)
MCD028	150	165.1	5	P	SiPySeCl(BaGaSp)
MCD028	165.1	165.2	5	P	CySePy
MCD028	165.2	176.4	5	P	SiSePyClFu(BaGaSp)
MCD028	176.4	178	5	P	CySeCl
MCD028	178	188.6	5	P	SiClPySe
MCD029	0	1.6	3	P	CyLi
MCD029	1.6	4.8	3	P	SiSe
MCD029	4.8	11.05	3	L	SiSe
MCD029	11.05	16.45	3	P	SiSe
MCD029	17	23.35	3	P	SiSeFu
MCD029	24.9	25.95	3	P	SiSe

MCD029	25.95	26.7	2	P	LiCy
MCD029	26.7	28.8	2	P	SiSeLiCy
MCD029	28.8	45.6	3	P	SiSe
MCD029	45.6	63.55	3	P	SeSi
MCD029	63.55	67.85	3	P	SiSe
MCD029	67.85	91.4	4	P	Se(Si)
MCD029	91.4	96.1	3	P	SiSe(Co)
MCD029	96.1	116.9	4	P	Se(Si)
MCD029	116.9	117.3	3	P	SeSi
MCD029	117.3	124	2	P	SeSi
MCD029	124	124.9	3	P	SiSe
MCD029	124.9	131.8	2	P	SeSi
MCD030	0	3.9	4	P/L	SiSePy/Li
MCD030	3.9	11.5	5	P	SiSePy
MCD030	11.5	16.7	5	P/L	SiSePy/FuBa
MCD030	16.7	28	5	P/KV	SiSePy/PyBa
MCD030	28	34	5	P/LV	SiSeClPy/BaQz
MCD030	34	52.2	5	P/KV/L	SiSeClPy/BaGaSpPy
MCD030	52.2	58.4	5	P/KV	SiSePy/BaGaSpPy
MCD030	58.4	68	5	P/KV	SiSeClPy/BaGaSpPy
MCD030	68	74.7	5	P/KV	SiSePy/BaGaSpPy
MCD030	74.7	82.2	5	P/LS	SiSeClPy/CyBa
MCD030	82.2	84.1	5	P/LV	SiSeClPy/BaGaSpPy
MCD030	84.1	89.8	5	P	SiSeClPy
MCD031	0	1	4	P/L	SiSePy/FuLi
MCD031	1	8.6	5	P/V	SiSePy/BaGaSpPy
MCD031	8.6	13.1	5	P/V	SiSeClPy/BaGaSpPy
MCD031	13.1	40	5	P/L	BaGaSpPy/SiSePy
MCD031	40	43.7	4	P/V	SiClSePy/BaGaSpPy,Qz,Py
MCD031	43.7	57.3	5	V/L	BaGaSpPy/SiSePy
MCD031	57.3	64.6	5	P/V	SiPyClSeFu/QzBaGaSpPy
MCD031	64.6	75.2	5	P/LS	SiPy/CyLi
MCD031	75.2	96.2	5	P/L	SiPySeCl/Fu
MCD031	96.2	110.3	5	P/LF	SiPyClSe/SiSePy